

# LIFE CYCLE ASSESSMENT FOR RAPIDLY EVOLVING TECHNOLOGIES

## A CASE STUDY ON GLOBAL INTEGRATED CIRCUIT MANUFACTURING

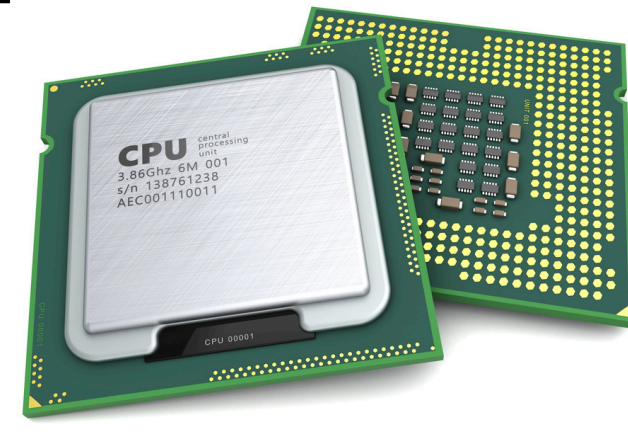
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### OVERVIEW <sup>1,2,3</sup>

- Information & Communication Technology (ICT) contributes 2-4% of global greenhouse gas emissions.
- Scope 3 upstream emissions can contribute 30-90% of total ICT emissions, depending on the product category.
- Integrated circuits are key contributors to upstream scope 3 emissions of data centers and computing systems.
- Companies are committing to reducing ICT emissions from upstream scope 3 but limited LCA data exists.



#### LCA DATA CHALLENGES

- Rapidly evolving products with wide variation in product category complexity
- Highly proprietary processing & ingredient information <sup>4,5</sup>
- Literature data from early 2000's
- Databases assume linear scaling properties but ignore nonlinear changes in processing technology and complexity

#### LCA DATA LIMITATIONS

- Data limited to specific geographies, processing tech
- Unaccounted nonlinearities
- Uncertainties in mitigation opportunities
- Difficult to compare across LCAs: minimal transparency and variable system boundaries and assumptions

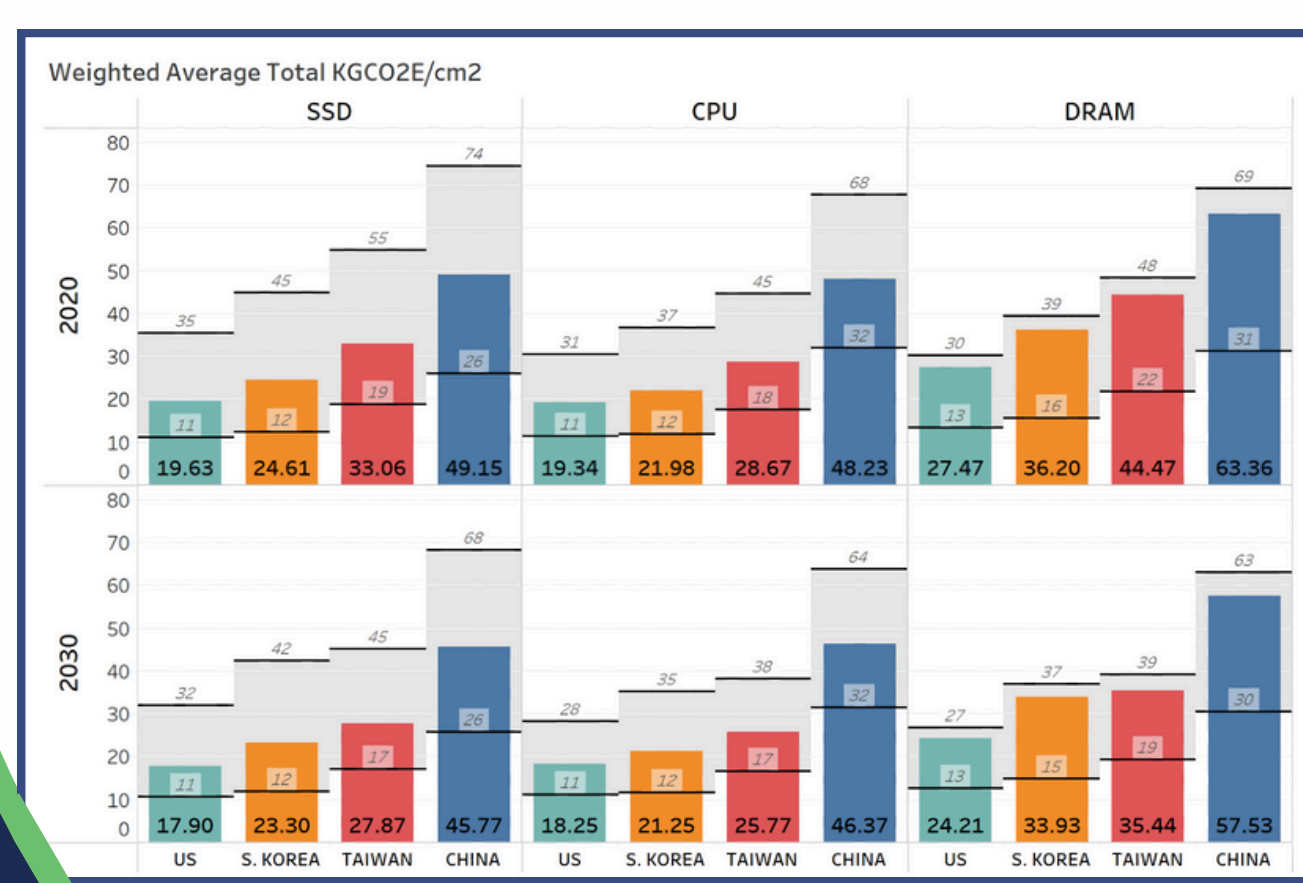
Poses significant challenges for accurate product LCA, scope 3 measurement and mitigation

### GOAL & SCOPE

Develop a parameterized, streamlined LCA to explore potential variation in semiconductor cradle-to-processing gate emissions across product types, product generations, regional production contexts, product technologies and design to identify potential levers for mitigating GHG emissions.

### EXAMPLE RANGE OF SIMULATED PRODUCTION POSSIBILITIES

2020 grid vs. 2030 grid decarb  
0-100% Renewable energy adoptions  
~16-20nm (default design parameters)  
0-100% F-gas abatement across tech types



#### LEVERAGE POINTS

- Renewable Energy
- 300mm Wafer Sizes
- SBTi Upstream Targets
- Remote Plasma Clean
- F-Gas Abatement

### DESIGN SCENARIO PARAMETERS

#### Simulation Model Scenario Parameters

- Fab size: [150-200mm, 300+mm]
- Country of production: [China, South Korea, Taiwan, US]
- Product type: [DRAM, SSD, CPU, GPU]
- Technology type: [In situ thermal clean, In situ plasma clean, Remote plasma clean]
- Gas replacement: [F2, C3F8, C4F8O, C4F8]
- Electricity management: [Renewables, Efficiency, grid decarbonization]
- Generation node: [90nm, 60nm, 40nm, 28nm, 20nm, 16nm, 10nm, 7nm, 5nm]
- Fabrication design details: [Deck stacking: single, 2D, 3D, 4D]
- Assembly design details: [Die stacking], [chips per package], [die size], [bit or transistor density], [defect density]
- Abatement technology/adoption: [combustion, hot-wet (electrical), plasma, catalytic]

#### Baseline default design assumptions

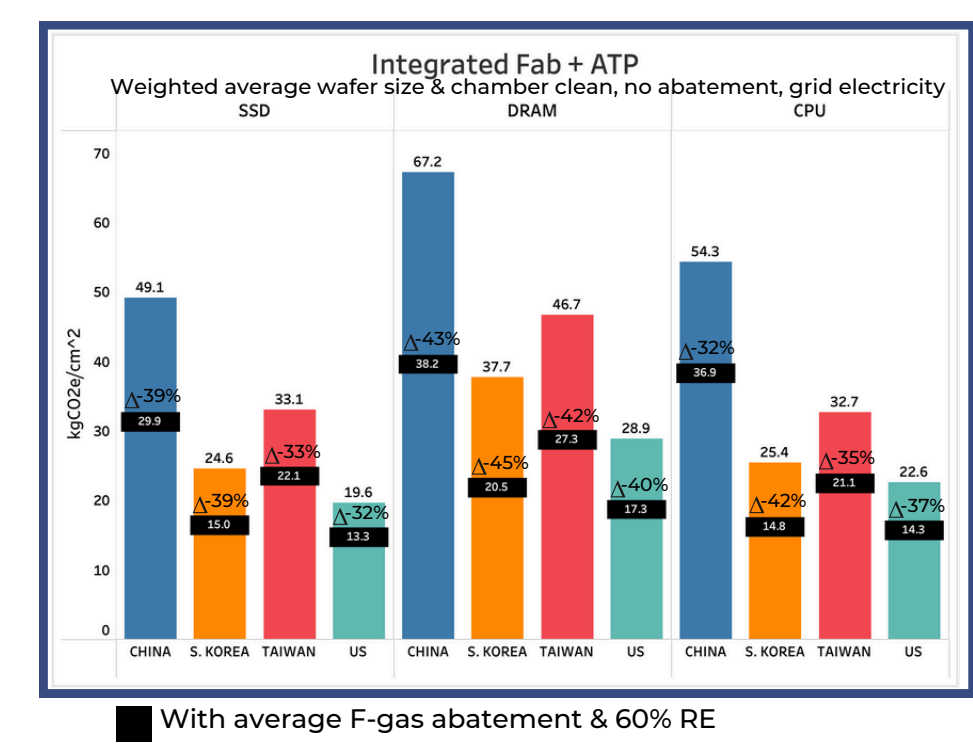
Parameters	SSD	DRAM	CPU
Node Generation	20nm	20nm	20nm
Capacity per Package	633 Gb	6 Gb	5,776 MTr
Deck Stacking	3D	2D	2D
Wafer Mask Layers	97	101	124
Size of die	118 mm <sup>2</sup>	53 mm <sup>2</sup>	312 mm <sup>2</sup>
Die per Wafer (200mm)	225	530	76
Die per Wafer (300mm)	537	1238	189
Bit or Transistor Density	5.4 Gb/mm <sup>2</sup>	0.1 Gb/mm <sup>2</sup>	19 MTr/mm <sup>2</sup>
Die stacking	1	1	1
Chips per Package	1	1	1
Defect Density (#/cm <sup>2</sup> /die)	0.1	0.1	0.1
Yield	89%	95%	74%

### EMISSIONS INTENSITY

GHG Emissions & Mitigation Opportunities vary by product category & country

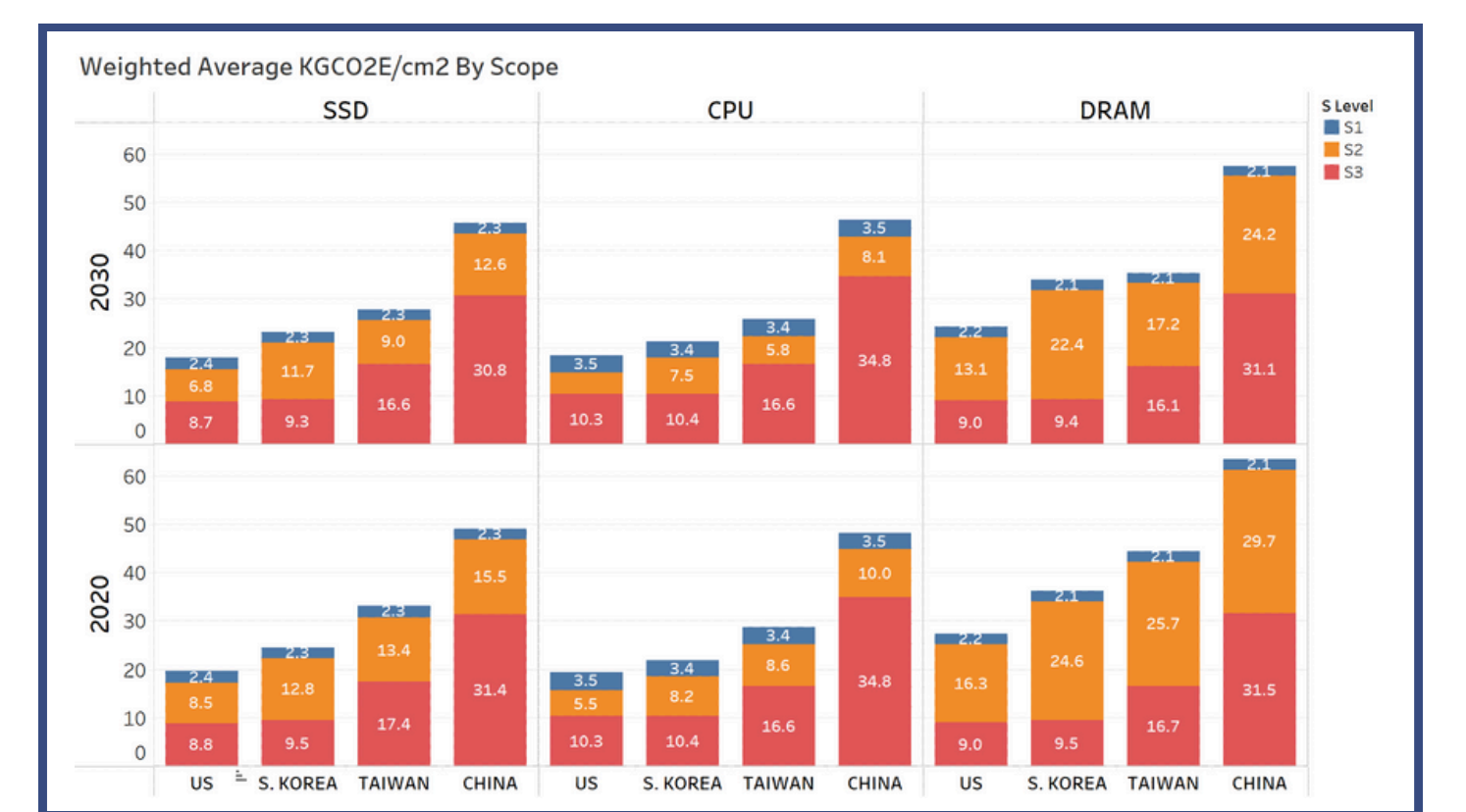
#### REDUCTION POTENTIAL

- SSD 32-39%
- DRAM 40-45%
- CPU 32-42%



Scope 2 emissions are biggest single hotspot

Scope 3 emissions vary by country and are a significant proportion of total emissions in aggregate



### METHODS <sup>6</sup>

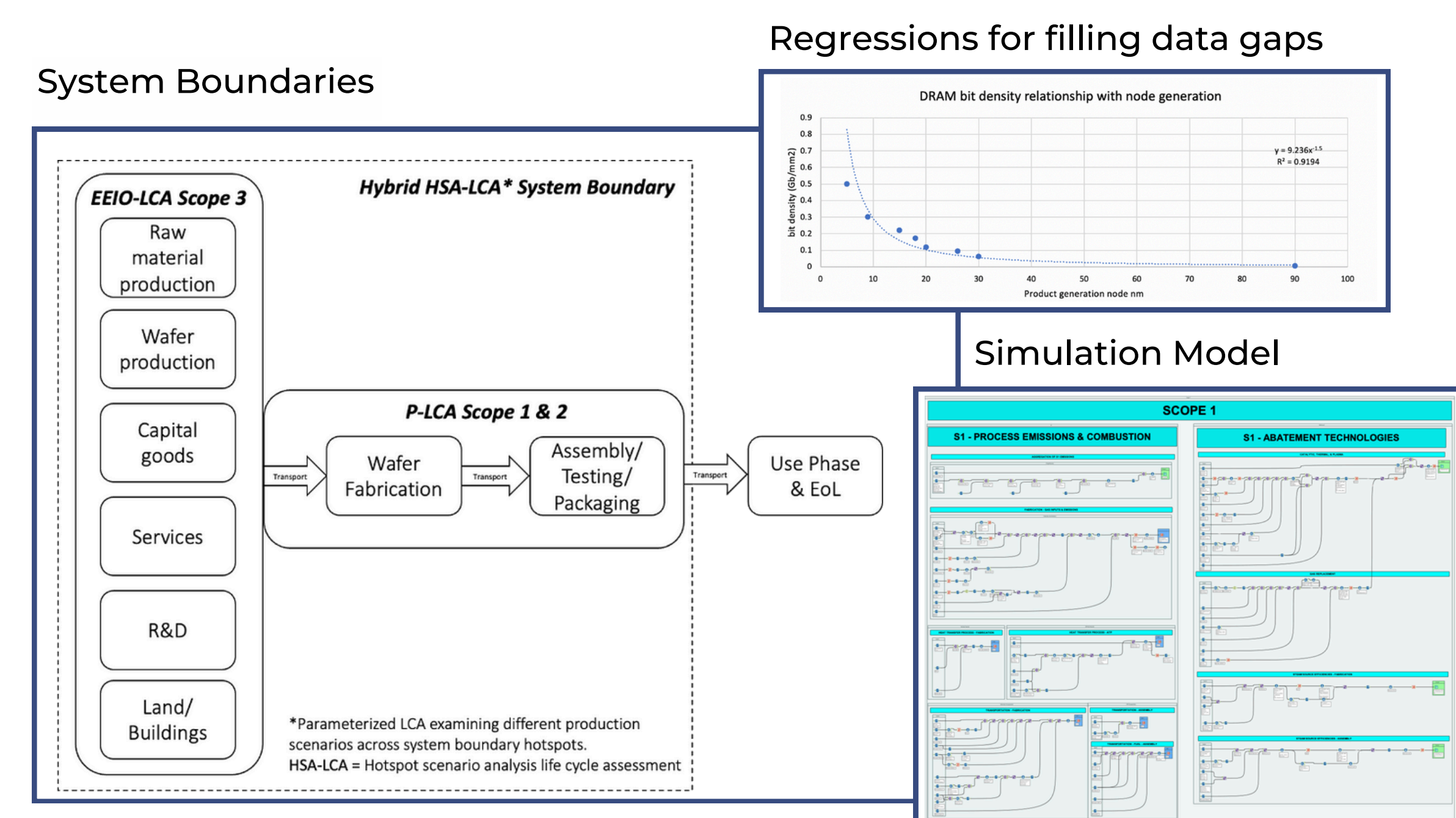
Identify hotspots through initial scoping analysis  
Fabrication | Assembly, Testing, Packaging (ATP)

2) Develop parameterized LCI within hotspot stages  
Govt Reports | Public Data | Regression Analysis of Gaps

3) Use general LCA information for non-hotspots  
EEIO | Existing PLCA's Reflecting Industry Averages

4) Identify key parameter levers affecting hotspot impacts  
Literature | Iterative Model Building | Sensitivity Analysis

5) Simulate discreet scenario permutations & estimate mitigation potential  
Capture dynamics across combinations of scenarios

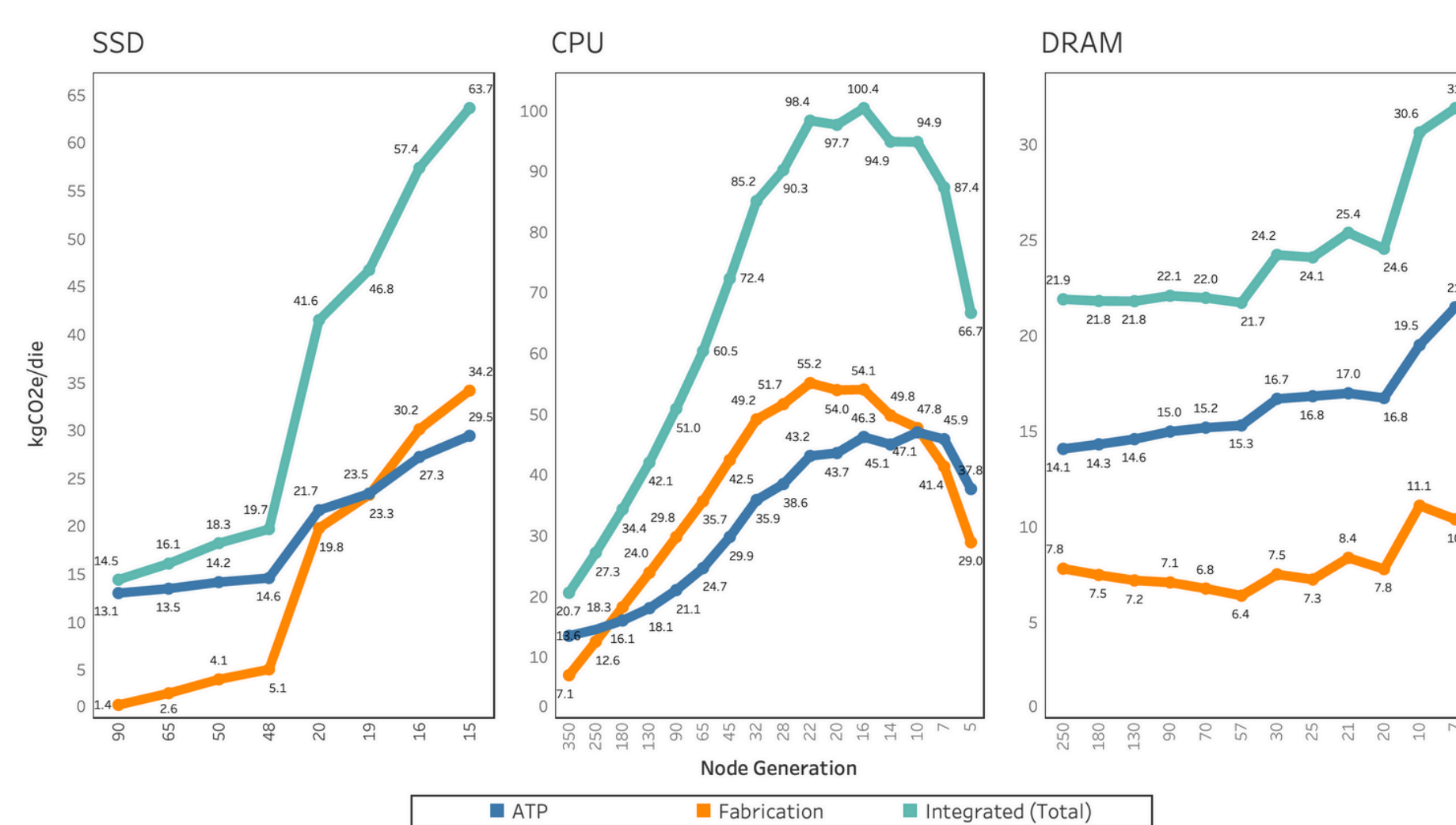


### GHG MITIGATION OPPORTUNITIES

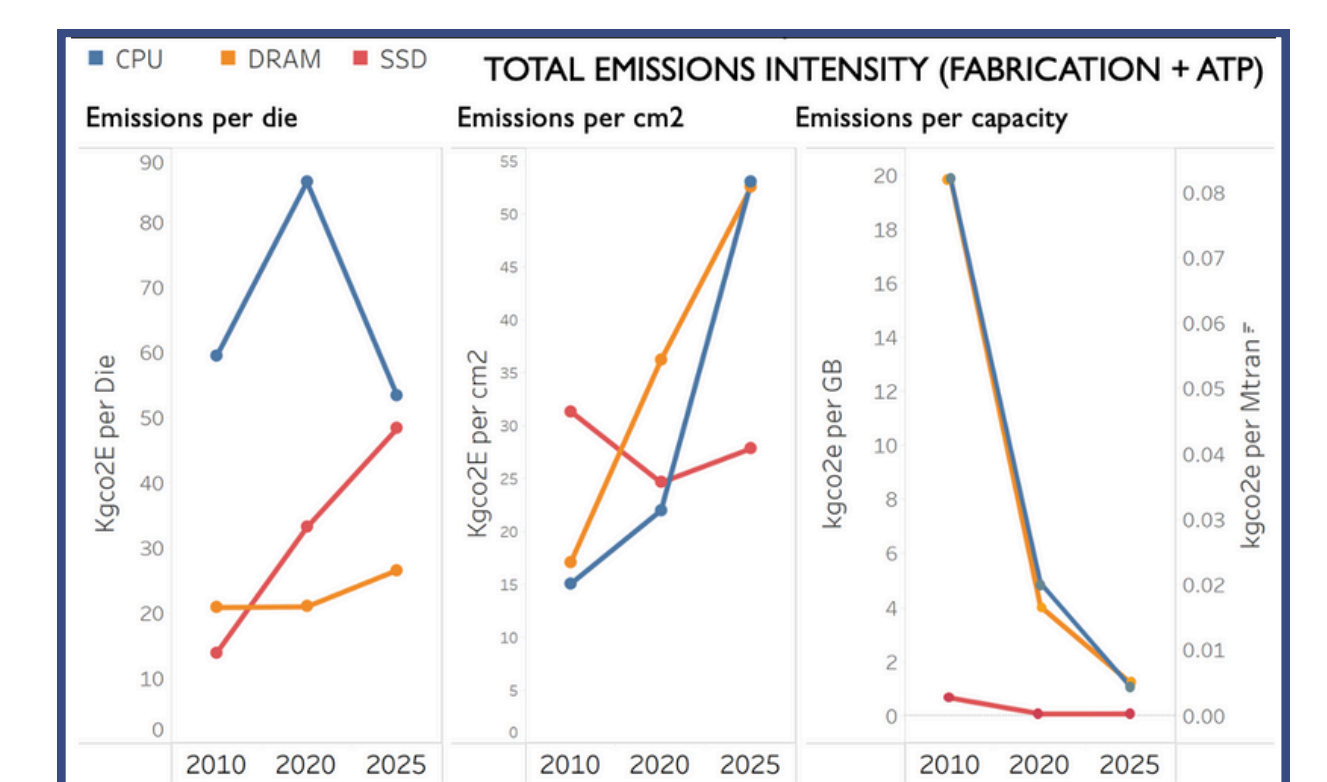
### SIMULATION DYNAMICS

Relative contribution from ATP vs. Fabrication production stages depends on product type and tech generation, having implications for supply chain engagement targets for how far to reach up the supply chain to effectively reduce emissions.

#### GHG Contributions Change across Tech Gens



#### GHG Trends Change across functional units



Emissions Intensity trends depend on the chosen functional unit, with implications for target setting:

- Generally increasing GHG per die & per cm<sup>2</sup> in newer generations
- Decreasing GHG per storage or processing capacity for newer product generations

#### Simulation Considerations:

- Product types
- Electricity
- Die size (mm<sup>2</sup>)
- Node generations
- Wafer mask layers

### BENEFITS OF PARAMETERIZED LCA

- Increase comparability across production & sourcing scenarios, avoiding inconsistent system boundaries, allocations, functional units, & other differences in assumptions.
- Enables prospective modeling for examining alternative production scenarios & mitigation options with enhanced comparability for directionally consistent decision signals.
- Reduces costs of analysis through parameterization & prioritizing high impact components of supply chain, which maintains comprehensiveness of the broader system.
- Increases timeliness & actionability of information for setting climate action plans & achieving targets.

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